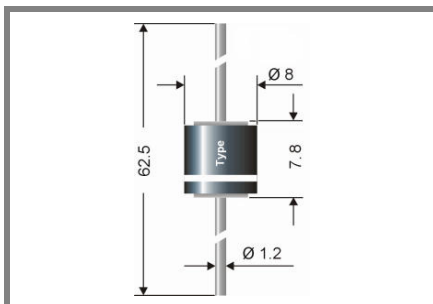


HE25FA ... HE25FG



Axial lead diode

| Type | Repetitive peak reverse voltage V_{RRM} V | Surge peak reverse voltage V_{RSM} V | Max. reverse recovery time $I_F = -A$ $I_R = -A$ $I_{RR} = -A$ t_{rr} ns | Max. forward voltage $V_F^{(2)}$ |
|---------|---|--|---|-------------------------------------|
| HE 25FA | 50 | 50 | 200 | 0,82 |
| HE 25FB | 100 | 100 | 200 | 0,82 |
| HE 25FD | 200 | 200 | 200 | 0,82 |
| HE 25FG | 400 | 400 | 200 | 0,82 |

High efficiency fast silicon rectifier diode

HE25FA ... HE25FG

Forward Current: 25 A

Reverse Voltage: 50 to 400 V

Preliminary Data

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

Mechanical Data

- Plastic case: 8 x 7,8 [mm]
- Weight approx.: 2,4 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 500 pieces per ammo or 1000 pieces per reel

1) Valid, if leads are kept at ambient temperature at distance of 0 mm from case

2) $I_F = 5 A$, $T_j = 25 ^\circ C$

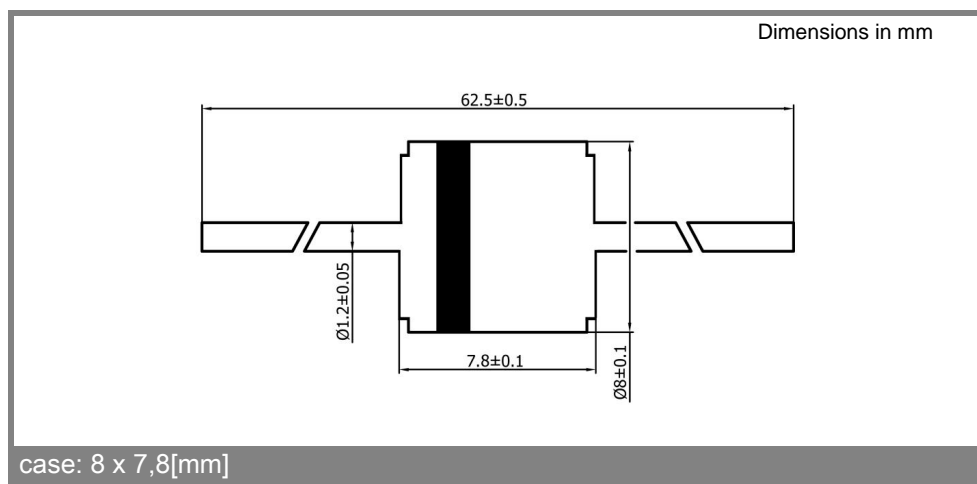
3) $T_A = 25 ^\circ C$

4) Thermal resistance from junction to lead/terminal at a distance 0 mm from case

5) Max. junction temperature $T_j \leq 185^\circ C$ in reverse mode $V_R = 50\% V_{RRM}$, $T_j \leq 200^\circ C$ in bypass mode

| Absolute Maximum Ratings | | TA = 25 °C, unless otherwise specified | |
|--------------------------|---|---|------------------|
| Symbol | Conditions | Values | Units |
| I_{FAV} | Max. averaged fwd. current, R-load, $T_A = 50 ^\circ C$ ¹⁾ | 25 | A |
| I_{FRM} | Repetitive peak forward current $f > 15 Hz$ ¹⁾ | 85 | A |
| I_{FSM} | Peak forward surge current 50 Hz half sinus-wave ³⁾ | 700 | A |
| i^2t | Rating for fusing, $t < 10 ms$ ³⁾ | 2450 | A ² s |
| R_{thA} | Max. thermal resistance junction to ambient ¹⁾ | | K/W |
| R_{thL} | Max. thermal resistance junction to terminals ⁴⁾ | 0,8 | K/W |
| T_j | Operating junction temperature | - 50 ... + 175 ($T_j \leq 200^\circ C$ ⁵⁾) | °C |
| T_s | Storage temperature | - 50 ... + 175 | °C |

| Characteristics | | TA = 25 °C, unless otherwise specified | |
|-----------------|---|--|-------|
| Symbol | Conditions | Values | Units |
| I_R | Maximum leakage current, $T_j = 25 ^\circ C$; $V_R = V_{RRM}$ | <25 | µA |
| | $T_j = ^\circ C$; $V_R = V_{RRM}$ | - | |
| C_J | Typical junction capacitance (at MHz and applied reverse voltage of V) | - | pF |
| Q_{rr} | Reverse recovery charge ($U_R = V$; $I_F = A$; $dI_F/dt = A/ms$) | - | µC |
| E_{RSM} | Non repetitive peak reverse avalanche energy ($I_R = mA$; $T_j = ^\circ C$; inductive load switched off) | - | mJ |



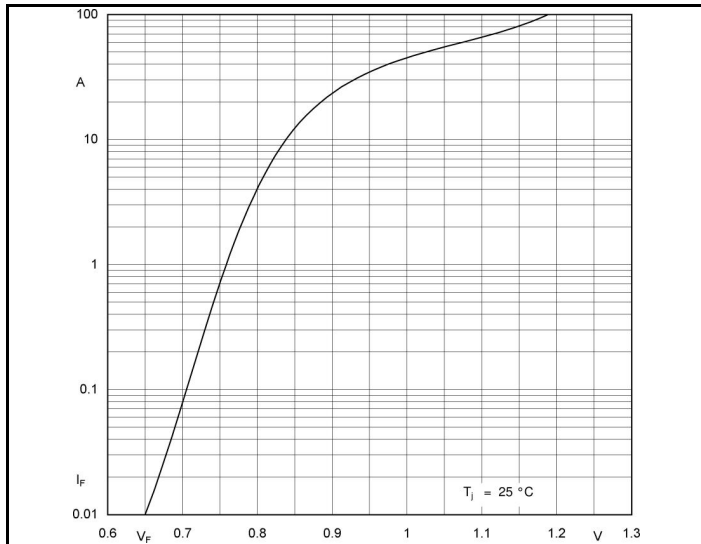


Fig. 1 Forward characteristics (typical values)

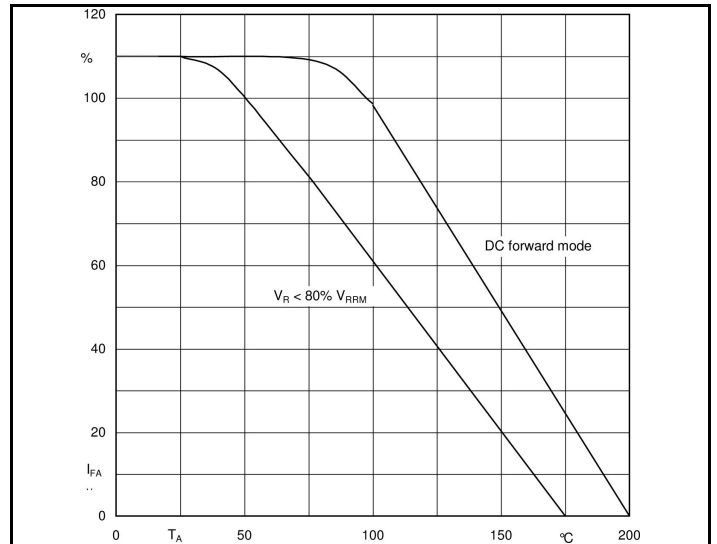


Fig. 2 Rated forward current vs. ambient temperature 1)

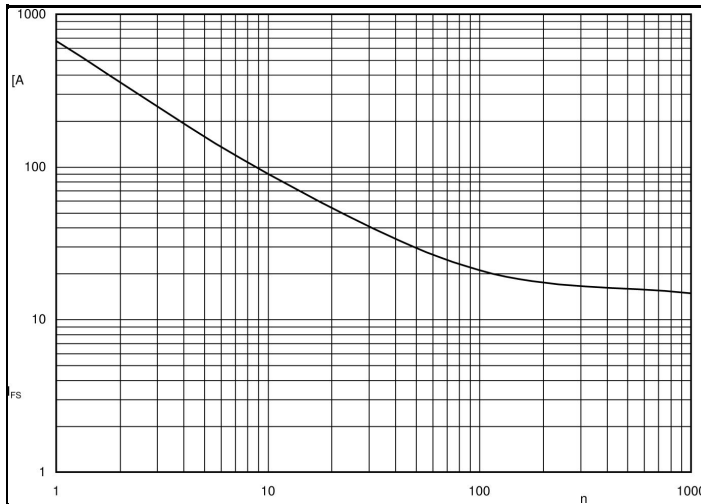


Fig. 4 I_{FSM} current versus number of cycles at 50 Hz

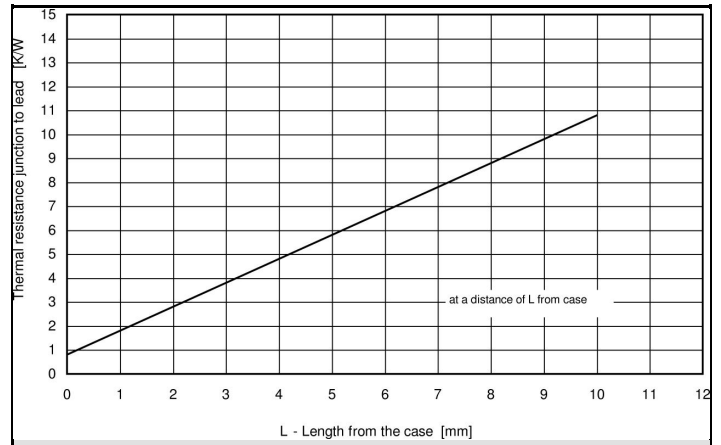


Fig. 4 Thermal resistance versus distance from case